TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7SZ86F,TC7SZ86FU

#### 2-Input EXCLUSIVE OR Gate

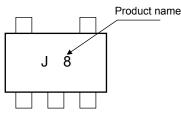
#### Features

- High output current :  $\pm 24 \text{ mA} (\text{min}) \text{ at } V_{CC} = 3 \text{ V}$
- Super high speed operation : t<sub>pd</sub>=2.9 ns (typ.)

at V<sub>CC</sub> = 5 V, 50 pF : V<sub>CC</sub> = 1.8 to 5.5 V

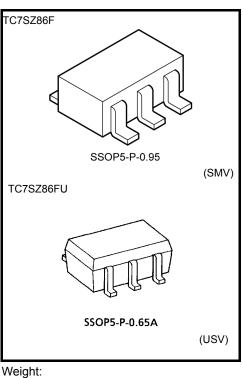
- Operating voltage range
- 5.5-V tolerant inputs.
- 5.5-V power down protection output.
- Matches the performance of TC74LCX series when operated at 3.3 V  $V_{CC}.$

#### Marking



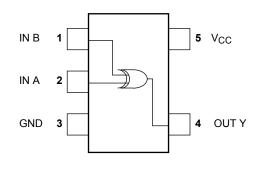
#### Absolute Maximum Ratings (Ta=25°C)

| Characteristics                    | Symbol           | Rating                                | Unit |  |
|------------------------------------|------------------|---------------------------------------|------|--|
| Supply voltage                     | V <sub>CC</sub>  | -0.5 to 6                             | V    |  |
| DC input voltage                   | V <sub>IN</sub>  | –0.5 to 6                             | V    |  |
| DC output voltage                  | Vout             | -0.5 to 6 (Note 1)                    | V    |  |
| DC output voltage                  | V001             | -0.5 to V <sub>CC</sub> +0.5 (Note 2) |      |  |
| Input diode current                | lıĸ              | -20                                   | mA   |  |
| Output diode current               | IOK              | -20 (Note 3)                          | mA   |  |
| DC output current                  | IOUT             | ±50                                   | mA   |  |
| DC V <sub>CC</sub> /ground current | ICC              | ±50                                   | mA   |  |
| Power dissipation                  | PD               | 200                                   | mW   |  |
| Storage temperature                | T <sub>stg</sub> | -65 to 150                            | °C   |  |
| Lead temperature (10 s)            | ΤL               | 260                                   | °C   |  |



SSOP5-P-0.95 SSOP5-P-0.65A

: 0.016 g (typ.) : 0.006 g (typ.)



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

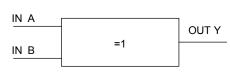
Note 1:  $V_{CC} = 0V$ 

Note 2: High or Low State. Do not exceed I<sub>OUT</sub> of absolute maximum ratings.

Note 3: V<sub>OUT</sub> < GND

# <u>TOSHIBA</u>

#### IEC Logic Symbol



| ٦ | Truth Table |   |   |  |  |  |  |  |
|---|-------------|---|---|--|--|--|--|--|
|   | А           | В | Y |  |  |  |  |  |
|   | L           | L | L |  |  |  |  |  |

| L | L | L |
|---|---|---|
| L | Н | Н |
| Н | L | Н |
| Н | Н | L |

#### **Operating Ranges**

| Characteristics          | Symbol           | Rating                                      | Unit |
|--------------------------|------------------|---|------|
| Supply voltage           | V <sub>CC</sub>  | 1.8 to 5.5                                  | V    |
|                          |                  | 1.5 to 5.5 (Note 4)                         | v    |
| Input voltage            | V <sub>IN</sub>  | 0 to 5.5                                    | V    |
| Output voltage           | V <sub>OUT</sub> | 0 to 5.5 (Note 5)                           | V    |
|                          |                  | 0 to V <sub>CC</sub> (Note 6)               | v    |
| Operating temperature    | T <sub>opr</sub> | -40 to 85                                   | °C   |
|                          | dt/dv            | 0 to 20 (V_{CC} = 1.8 V, 2.5 V $\pm$ 0.2 V) |      |
| Input rise and fall time |                  | 0 to 10 (V_{CC} = 3.3 V $\pm$ 0.3 V)        | ns/V |
|                          |                  | 0 to 5 (V_{CC} = 5.0 V $\pm$ 0.5 V)         |      |

Note 4: Data retention only

Note 5:  $V_{CC} = 0 V$ 

Note 6: High or Low state

#### **Electrical Characteristics**

#### **DC Characteristics**

| Characteristics   |             | Symbol Test Condition |   | Condition                 |               | Ta = 25°C                 |      | Ta = -40 to<br>85°C       |  | Unit                      |     |
|---|-------------|-----------------------|---|---------------------------|---------------|---------------------------|------|---------------------------|--|---------------------------|-----|
|   |             |                       |   |                           | $V_{CC}(V)$   | Min                       | Тур. | Max                       | Min  | Max                       |     |
| High level  | High lovel  |                       | _   |                           | 1.8           | V <sub>CC</sub><br>× 0.75 |      | _                         | $\begin{array}{c} V_{CC} \\ \times \ 0.75 \end{array}$ |                           | - V |
|   | rligirievei | VIH                   |   |                           | 2.3 to<br>5.5 | $V_{CC} \times 0.7$       |      | _                         | $V_{CC} \times 0.7$                                    | _                         |     |
| Input voltage   | Low level   | VIL                   | _   |                           | 1.8           | _                         | _    | V <sub>CC</sub><br>× 0.25 | _  | V <sub>CC</sub><br>× 0.25 |     |
|   | LOW IEVEI   | VIL                   |   |                           | 2.3 to<br>5.5 | _                         | _    | V <sub>CC</sub><br>× 0.3  | _  | V <sub>CC</sub><br>× 0.3  |     |
|   |             |                       |   |                           | 1.8           | 1.7                       | 1.8  | _                         | 1.7  | _                         | V   |
|   |             |                       | V <sub>IN</sub> = V <sub>IH</sub><br>or V <sub>IL</sub> | I <sub>OH</sub> = −100 μA | 2.3           | 2.2                       | 2.3  | _                         | 2.2  | _                         |     |
|   |             |                       |   | 10H = -100 μA             | 3.0           | 2.9                       | 3.0  | _                         | 2.9  |                           |     |
|   | High level  | Vон                   |   |                           | 4.5           | 4.4                       | 4.5  | —                         | 4.4  | —                         |     |
|   | riigirievei | VOH                   |   | I <sub>OH</sub> = -8 mA   | 2.3           | 1.9                       | 2.15 | —                         | 1.9  | —                         |     |
|   |             |                       |   | $I_{OH} = -16 \text{ mA}$ | 3.0           | 2.4                       | 2.8  | —                         | 2.4  | —                         |     |
|   |             |                       |   | $I_{OH} = -24 \text{ mA}$ | 3.0           | 2.3                       | 2.68 | —                         | 2.3  | —                         |     |
| Output voltage  |             |                       |   | I <sub>OH</sub> = -32 mA  | 4.5           | 3.8                       | 4.2  | —                         | 3.8  | —                         |     |
| o alpar ronago  |             |                       |   | I <sub>OL</sub> = 100 μΑ  | 1.8           | —                         | 0    | 0.1                       | —  | 0.1                       |     |
|   |             |                       |   |                           | 2.3           | _                         | 0    | 0.1                       | _  | 0.1                       |     |
|   |             |                       |   |                           | 3.0           | _                         | 0    | 0.1                       | _  | 0.1                       |     |
|   | Low level   | V <sub>OL</sub>       |   |                           | 4.5           | —                         | 0    | 0.1                       | —  | 0.1                       | V   |
|   |             | 0L                    |   | I <sub>OL</sub> = 8 mA    | 2.3           | _                         | 0.1  | 0.3                       | —  | 0.3                       |     |
|   |             |                       |   | I <sub>OL</sub> = 16 mA   | 3.0           | _                         | 0.15 | 0.4                       | —  | 0.4                       |     |
|   |             |                       |   | I <sub>OL</sub> = 24 mA   | 3.0           |                           | 0.22 | 0.55                      |  | 0.55                      |     |
|   |             |                       |   | I <sub>OL</sub> = 32 mA   | 4.5           |                           | 0.22 | 0.55                      | —  | 0.55                      |     |
| Input leakage current $I_{IN}$ $V_{IN} = 5.5$ V or GND  |             |                       | 0 to 5.5  |                           |               | ±1                        |      | ±10                       | μA   |                           |     |
| Power off leakage current $I_{OFF}$ $V_{IN}$ or $V_{OUT} = 5.5$ V   |             |                       | 0.0   |                           |               | 1                         |      | 10                        | μA   |                           |     |
| $\label{eq:Quiescent supply current} Quiescent supply current \qquad I_{CC} \qquad V_{IN} = V_{CC} \text{ or } GND$ |             | 5.5                   | —   | —                         | 2             | —                         | 20   | μA                        |  |                           |     |

#### AC Characteristics (unless otherwise specified, Input: $t_r = t_f = 3 \text{ ns}$ )

| Characteristics               | Symbol                   | Test Condition                                      |                                | Ta = 25°C |      | Ta = -40 to<br>85°C |     | Unit |      |
|-------------------------------|--------------------------|---|--------------------------------|-----------|------|---------------------|-----|------|------|
|                               |                          |   | V <sub>CC</sub> (V)            | Min       | Тур. | Max                 | Min | Max  |      |
| Propagation delay time        | <sup>t</sup> pLH<br>tpHL | $C_L = 15 \text{ pF},$<br>$R_L = 1 \text{ M}\Omega$ | $\textbf{1.8}\pm\textbf{0.15}$ | 2.0       | 5.7  | 11.5                | 2.0 | 12.0 | - ns |
|                               |                          |   | $\textbf{2.5}\pm\textbf{0.2}$  | 0.8       | 3.8  | 8.0                 | 0.8 | 8.5  |      |
|                               |                          |   | $\textbf{3.3}\pm\textbf{0.3}$  | 0.5       | 3.0  | 5.7                 | 0.5 | 6.0  |      |
|                               |                          |   | $5.0\pm0.5$                    | 0.5       | 2.4  | 5.0                 | 0.5 | 5.4  |      |
|                               |                          | $C_L = 50 \text{ pF},$<br>$R_L = 500 \Omega$        | $\textbf{3.3}\pm\textbf{0.3}$  | 1.2       | 3.5  | 6.2                 | 1.2 | 6.5  | - ns |
|                               |                          |   | $5.0\pm0.5$                    | 0.8       | 2.9  | 5.4                 | 0.8 | 5.8  |      |
| Input capacitance             | C <sub>IN</sub>          | —   | 0 to 5.5                       | —         | 4    | _                   | _   | —    | pF   |
| Power dissipation capacitance | C <sub>PD</sub>          | (Note 7)  | 3.3                            | _         | 21   | _                   | _   |      | pF   |
|                               |                          |   | 5.5                            | _         | 24   | _                   | _   | _    |      |

Note 7: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

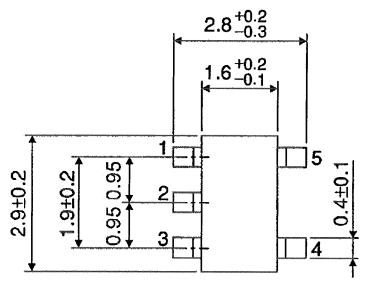
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

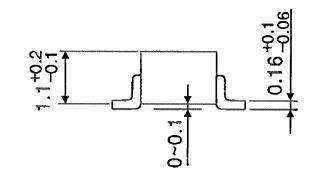
## <u>TOSHIBA</u>

#### Package Dimensions

SSOP5-P-0.95

Unit : mm



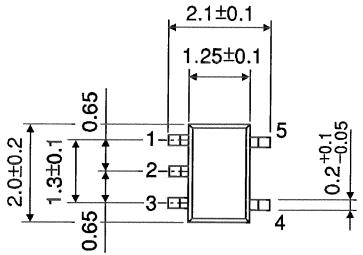


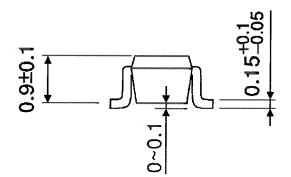
Weight: 0.016 g (typ.)

### <u>TOSHIBA</u>

#### Package Dimensions

Unit : mm





Weight: 0.006 g (typ.)

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